

MK0514 LDMOS TRANSISTOR

Document Number: MK0514
Product Datasheet V1.0

140W, 28V High Power RF LDMOS FETs

Description

The MK0514 is a 140-watt, highly rugged, unmatched LDMOS FET, designed for wide-band commercial and industrial applications with frequencies HF to 1 GHz. It can be used in Class AB/B and Class C for all typical modulation formats.

•Typical Performance (On Innogration fixture with device soldered):

$V_{DD} = 28$ Volts, $I_{DQ} = 800$ mA, CW.

| Frequency | Gp (dB) | P_{-1dB} (W) | $\eta_D@P_{-1}$ (%) |
|-----------|---------|----------------|---------------------|
| 1000 MHz | 18 | 140 | 60 |

Features

- High Efficiency and Linear Gain Operations
- Integrated ESD Protection
- Excellent thermal stability, low HCI drift
- Large Positive and Negative Gate/Source Voltage Range for Improved Class C Operation
- Pb-free, RoHS-compliant

Suitable Applications

- 2-30MHz (HF or Short wave communication)
- 30-88MHz (Ground communication)
- 54-88MHz (TV VHF I)
- 88-108MHz (FM)
- 118 -140MHz (Avionics)
- 136-174MHz (Commercial ground communication)
- 160-230MHz (TV VHF III)
- 30-512MHz (Jammer, Ground/Air communication)
- 470-860MHz (TV UHF)
- 100kHz - 1000MHz (ISM, instrumentation)

Table 1. Maximum Ratings

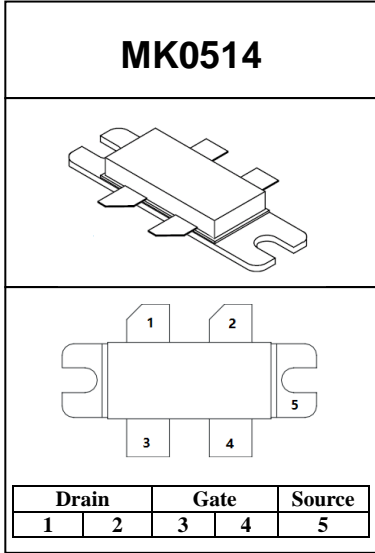
| Rating | Symbol | Value | Unit |
|--------------------------------|-----------|-------------|------|
| Drain--Source Voltage | V_{DS} | +95 | Vdc |
| Gate--Source Voltage | V_{GS} | -10 to +10 | Vdc |
| Operating Voltage | V_{DD} | +40 | Vdc |
| Storage Temperature Range | T_{stg} | -65 to +150 | °C |
| Case Operating Temperature | T_c | +150 | °C |
| Operating Junction Temperature | T_J | +225 | °C |

Table 2. Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|-----------------|-------|------|
| Thermal Resistance, Junction to Case $T_C = 85^{\circ}\text{C}$, $T_J = 200^{\circ}\text{C}$, DC test | $R_{\theta JC}$ | 0.4 | °C/W |

Table 3. ESD Protection Characteristics

| Test Methodology | Class |
|-------------------------------------|---------|
| Human Body Model (per JESD22--A114) | Class 2 |



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Table 4. Electrical Characteristics ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|--|---------------|-----|------|-----|---------------|
| DC Characteristics (per half section) | | | | | |
| Drain-Source Voltage $V_{GS}=0, I_{DS}=1.0\text{mA}$ | $V_{(BR)DSS}$ | 95 | | | V |
| Zero Gate Voltage Drain Leakage Current ($V_{DS} = 75\text{V}, V_{GS} = 0\text{V}$) | I_{DSS} | — | — | 1 | μA |
| Zero Gate Voltage Drain Leakage Current ($V_{DS} = 28\text{V}, V_{GS} = 0\text{V}$) | I_{DSS} | — | — | 1 | μA |
| Gate--Source Leakage Current ($V_{GS} = 10\text{V}, V_{DS} = 0\text{V}$) | I_{GSS} | — | — | 1 | μA |
| Gate Threshold Voltage ($V_{DS} = 28\text{V}, I_D = 400\text{ }\mu\text{A}$) | $V_{GS(th)}$ | — | 2.2 | — | V |
| Gate Quiescent Voltage ($V_{DD} = 28\text{V}, I_D = 800\text{mA}$, Measured in Functional Test) | $V_{GS(Q)}$ | — | 3.1 | — | V |
| Common Source Input Capacitance ($V_{GS} = 0\text{V}, V_{DS} = 28\text{V}, f = 1\text{MHz}$) | C_{ISS} | | 70 | | pF |
| Common Source Output Capacitance ($V_{GS} = 0\text{V}, V_{DS} = 28\text{V}, f = 1\text{MHz}$) | C_{OSS} | | 29.5 | | pF |
| Common Source Feedback Capacitance ($V_{GS} = 0\text{V}, V_{DS} = 28\text{V}, f = 1\text{MHz}$) | C_{RSS} | | 1.1 | | pF |

Functional Tests (In Demo Test Fixture, 50 ohm system) $V_{DD} = 28\text{Vdc}$, $I_{DQ} = 1000\text{mA}$, $f = 800\text{MHz}$, CW Signal Measurements.

| | | | | | |
|------------------------|------------|---|-----|---|----|
| Power Gain | G_p | — | 18 | — | dB |
| Drain Efficiency@P1dB | η_D | — | 60 | — | % |
| 1 dB Compression Point | P_{-1dB} | — | 140 | — | W |
| Input Return Loss | IRL | — | -7 | — | dB |

Load Mismatch (In Innogration Test Fixture, 50 ohm system): $V_{DD} = 28\text{Vdc}$, $I_{DQ} = 800\text{mA}$, $f = 1000\text{MHz}$

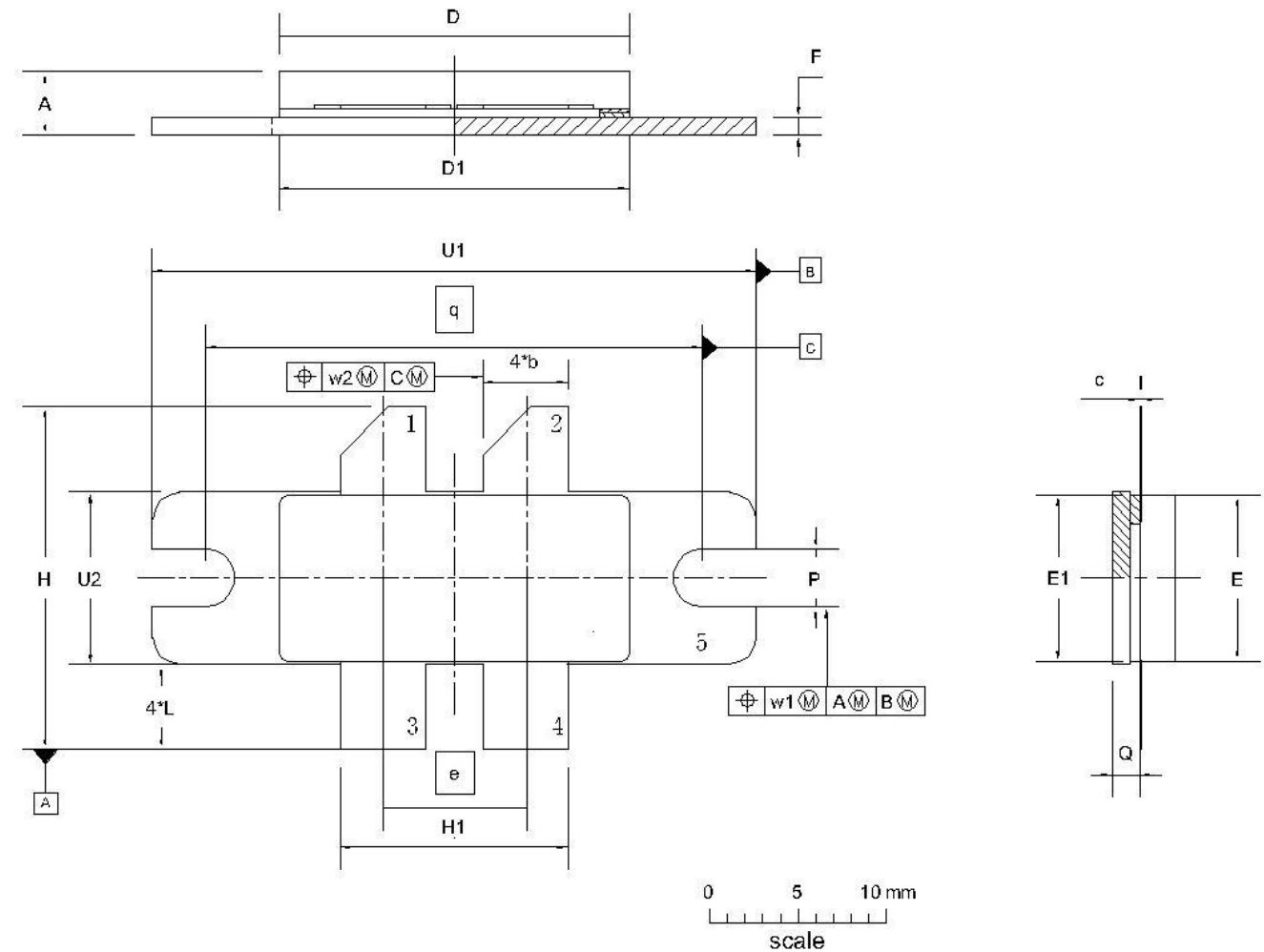
| | |
|---|-----------------------|
| VSWR 20:1 at 140W pulse CW Output Power | No Device Degradation |
|---|-----------------------|

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Package Outline

Flanged ceramic package; 2 mounting holes; 4 leads



| UNIT | A | b | c | D | D ₁ | e | E | E ₁ | F | H | H ₁ | L | p | Q | q | U ₁ | U ₂ | W ₁ | W ₂ |
|--------|-------|-------|-------|-------|----------------|------|-------|----------------|-------|-------|----------------|-------|-------|-------|-------|----------------|----------------|----------------|----------------|
| mm | 4.72 | 3.94 | 0.15 | 20.02 | 19.96 | 8.89 | 9.50 | 9.53 | 1.14 | 19.94 | 12.83 | 5.33 | 3.38 | 1.70 | 27.94 | 34.16 | 9.91 | 0.25 | 0.51 |
| | 3.43 | 3.68 | 0.08 | 19.61 | 19.66 | | 9.30 | 9.25 | 0.89 | 18.92 | 12.57 | 4.32 | 3.12 | 1.45 | | 33.91 | 9.65 | | |
| inches | 0.186 | 0.155 | 0.006 | 0.788 | 0.786 | 0.35 | 0.374 | 0.375 | 0.045 | 0.785 | 0.505 | 0.210 | 0.133 | 0.067 | 1.100 | 1.345 | 0.390 | 0.01 | 0.02 |
| | 0.135 | 0.145 | 0.003 | 0.772 | 0.774 | | 0.366 | 0.364 | 0.035 | 0.745 | 0.495 | 0.170 | 0.123 | 0.057 | | 1.335 | 0.380 | | |

| OUTLINE VERSION | REFERENCE | | | EUROPEAN PROJECTION | ISSUE DATE |
|--------------------|-----------|-------|-------|------------------------|------------|
| | IEC | JEDEC | JEITA | | |
| PKG-B4E | | | | | 03/12/2013 |

Revision history

Table 5. Document revision history

| Date | Revision | Datasheet Status |
|----------|----------|-------------------|
| 2017/4/6 | Rev 1.0 | Product Datasheet |
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